COMPMECH



Lattice orientation and crack size effect on the mechanical properties of Graphene

P. R. Budarapu · B. Javvaji · V. K. Sutrakar · D. Roy Mahapatra · M. Paggi · G. Zi · T. Rabczuk

Received: 26 January 2016 / Accepted: 11 April 2016 © Springer Science+Business Media Dordrecht 2016

Abstract The effect of lattice orientation and crack length on the mechanical properties of Graphene are 2 studied based on molecular dynamics simulations. 3 Bond breaking and crack initiation in an initial edge 4 crack model with 13 different crack lengths, in 10 dif-5 ferent lattice orientations of Graphene are examined. 6 In all the lattice orientations, three recurrent fracture patterns are reported. The influence of the lattice ori-8 entation and crack length on yield stress and yield strain 9 of Graphene is also investigated. The arm-chair fracture 10 pattern is observed to possess the lowest yield properties. A sudden decrease in yield stress and yield strain 12

can be noticed for crack sizes <10nm. However, for

P. R. Budarapu (🖂) · M. Paggi IMT School for Advanced Studies Lucca, Piazza San Fracensco 19, 55100 Lucca, Italy e-mail: pattabhi.budarapu@imtlucca.it

B. Javvaji · D. Roy Mahapatra Department of Aerospace Engineering, Indian Institute of Science, Bangalore 560012, India

V. K. Sutrakar

Aeronautical Development Agency, Defence Research and Development Organization, Bangalore 560017, India

G. Zi · T. Rabczuk

School of Civil, Environmental and Architectural Engineering, Korea University, Seoul 136-701, Korea

T. Rabczuk

Institute of Structural Mechanics, Bauhaus University of Weimar, 99423 Weimar, Germany

larger crack sizes, a linear decrease in yield stress is 13 observed, whereas a constant yield strain of ≈ 0.05 is 14 noticed. Therefore, the yield strain of ≈ 0.05 can be con-15 sidered as a critical strain value below which Graphene 16 does not show failure. This information can be utilized 17 as a lower bound for the design of nano-devices for var-18 ious strain sensor applications. Furthermore, the yield 19 data will be useful while developing the Graphene coat-20 ing on Silicon surface in order to enhance the mechan-21 ical and electrical characteristics of solar cells and to 22 arrest the growth of micro-cracks in Silicon cells. 23

Keywords Graphene fracture · Molecular dynamics · Bond elongation and rotation · Lattice orientation and initial crack size

1 Introduction

Graphene, an ultimately thin monolayer of carbon 28 atoms packed into a hexagonal lattice, is the basic build-29 ing block for graphitic materials of all other dimen-30 sionalities (Geim 2009; Huhu et al. 2014; Morpurgo 31 2015; Ying-Yan et al. 2014). Because of its several use-32 ful material properties (Changgu et al. 2008; Fengnian 33 et al. 2014; Fiori et al. 2014; Kravets et al. 2014; Mics 34 et al. 2015; Sarma et al. 2011; Schwierz 2010; Wei-35 wei et al. 2015), Graphene finds wide range of applica-36 tions (Budarapu et al. 2009, 2014c; Kinam et al. 2011; 37 Kostarelos and Novoselov 2014; Liu 2014; Pospischil 38 et al. 2014; Quan et al. 2015; Rodrigues et al. 2015; San-39

🖉 Springer

24

25

26

27

P. R. Budarapu et al.

89

90

91

92

93

94

95

96

134

tanu et al. 2012; Son et al. 2015; Traversi et al. 2014; 40 Wen et al. 2012; Xue et al. 2014; Xuechao et al. 2015; 41 Zhang et al. 2013). It can also be used as a strength-42 ening component in composites (Chen et al. 2015a; 43 Kim et al. 2013; Shin et al. 2015; Zan et al. 2015). As 44 the demand for Graphene-based applications is grow-45 ing, it is important to deeply understand it's mechan-46 ical and challenging failure characteristics. Chuvilin 47 et al. (2009) studied the growth of two holes created 48 by radiation in Graphene nano ribbons, based on the 49 imaging side spherical aberration-corrected transmis-50 sion electron microscopy at 80kV. As the holes grow 51 and two holes approach each other, they observed the 52 transitions and deviations from the hexagonal struc-53 ture involving some reconstructions resulting into more 54 pentagons and heptagons than hexagons, which turned 55 out to be stable. Jin et al. (2009) explained the struc-56 tural dynamics of carbon atomic chains such as forma-57 tion, migration, and breakage observed in the experi-58 ments, by density-functional theory calculations. How-59 ever, estimating the mechanical properties of Graphene 60 is challenging due to the practical difficulties in setting-61 up experiments (Kim et al. 2012). Hence, numerical 62 simulations are good alternatives for predicting frac-63 ture related properties. Several researchers have inves-64 tigated the mechanical properties of Graphene based on 65 molecular dynamics simulations (Chen et al. 2015b; 66 Gamboa et al. 2015; Grantab et al. 2010; Hadden 67 et al. 2015; Pei et al. 2010; Tiwary et al. 2015a,b; 68 Vadukumpully et al. 2011). 69

Bu et al. (2009) investigated the mechanical behav-70 ior of Graphene nanoribbons based on Tersoff poten-71 tial function. They reported the increase in the Young's 72 modulus due to stress stiffening, when the strain 73 exceeds 18%. Peng et al. (2014) have measured the 74 fracture toughness of Graphene based on experiments, 75 validated with numerical simulations. They also ver-76 ified the applicability of the classic Griffith theory 77 of brittle fracture to Graphene. They observed that 78 the critical stress intensity factor (K_{IC}) is not con-79 stant when the initial crack length is less than a cer-80 tain value. Ansari et al. (2012) have studied the pres-81 ence of vacancy defects in Graphene based on the 82 Tersoff-Brenner potential function and reported signif-83 icant reduction in the ultimate strength in the zig-zag 84 direction, while the effect is minimal on the Young's 85 modulus. Khare et al. (2007) have studied the effects 86 of large defects and cracks on the mechanical prop-87 erties of carbon nanotubes and Graphene sheets using 88

the coupled quantum mechanical/molecular mechanical approach based on the Tersoff-Brenner potential. They observed that the weakening effects of holes, slits, and cracks will vary only moderately with the shape of the defect, and instead depend primarily on the crosssection of the defect perpendicular to the loading direction and on the structure near the fracture initiation point.

Jhon et al. (2012, 2014) estimated the anisotropic 97 fracture response of Graphene based on molecular 98 dynamics simulations. They found that both the ten-99 sile strength and strain remain almost constant up to an 100 orientation angle of 12°. Then a rapid increase resulting 101 in a remarkable degradation of the tensile strength com-102 pared to brittle fracture counterpart, was reported. They 103 also noticed that fracture pattern holds in the range 100-104 700 K. Sun et al. (2015) investigated the orientational 105 anisotropic effect on the fracture strength of vacancy-106 defective Graphene using molecular dynamics simu-107 lations. They concluded that the fracture strength of 108 Graphene at the orientation angle of 15° has the small-109 est sensitivity to vacancy defects due to the minimiza-110 tion of stress concentration in that direction. Also, the 111 fracture strength in the zig-zag direction was found to 112 be more sensitive to the vacancy defects. Cao (2014) 113 used the quantum mechanical and classical molecu-114 lar dynamics simulations to understand the mechani-115 cal behavior of Graphene. However, the above studies 116 were carried out on Graphene without initial cracks. 117 Hence, the effect of lattice orientation on the crack 118 growth dynamics was ignored. 119

Zhao et al. (2009) have investigated the mechan-120 ical strength and properties of Graphene under uni-121 axial tensile test as a function of size and chirality 122 using the orthogonal tight-binding method and molecu-123 lar dynamics simulations with an adaptive intermolecu-124 lar reactive empirical bond order (AIREBO) potential. 125 They reported reasonable agreement of their estimated 126 results on Young's modulus, fracture strain and fracture 127 strength of bulk Graphene, with the published exper-128 imental data (Changgu et al. 2008; Liu et al. 2007). 129 They also observed that the Griffith criterion overes-130 timates the strength of cracks shorter than 10nm and 131 hence used a strength based criterion to explain the 132 vield behaviour. 133

Recently, Datta et al. (2015) have investigated:

1. The effect of two lattice orientations (arm-chair and 135 zig-zag) with different crack lengths (for a/b ratios 136

Deringer

Journal: 10704-FRAC MS: 0115 TYPESET DISK LE CP Disp.:2016/5/18 Pages: 18 Layout: Medium

138

upto 0.25) in mixed mode loading conditions at 300 and 1000 K, while keeping the crack perpendicular to the orientations.

2. The effect of crack orientation in the arm-chair and zig-zag Graphene, retaining the same loading directions.

Their main objective is to study the fracture toughness, 143 using the AIREBO potential function. In the present 144 work, we study 10 different orientations with 13 differ-145 ent crack lengths. We always load Graphene along the 146 direction perpendicular to the crack length to study the 147 Mode I fracture. This is similar to the first case inves-148 tigated in Datta et al. (2015) for arm-chair and zig-zag 149 Graphene. In the present work, our focus is mainly on 150 estimating the mechanical properties of Graphene and 151 the coupled effect of the lattice orientations and initial 152 crack length on the mechanical properties, based on 153 the Tersoff potential function. Therefore, the relations 154 between the lattice orientation and the crack pattern and 155 between the initial crack size and lattice orientation on 156 the mechanical properties of Graphene are investigated. 157 The final aim is to come up with a design criterion 158 which can be used in the nano-devices for strain sensor 159 applications. 160

The followings are the main objectives of the present 161 study: (1) identification of limiting strain below which 162 Graphene never fails; (2) combined effect of the lattice 163 orientation and crack size on the mechanical properties 164 of Graphene; (3) identification of fracture pattern for 165 each given lattice orientation; and (4) the variation of 166 the tensile strength with chiral angle. All the above 167 results are important for the design of Graphene-based 168 nano devices. 169

The arrangement of the article is as follows: Details of the numerical model are explained in Sect. 2. The effect of lattice orientation and crack size in the yield properties of Graphene are discussed in Sect. 3. The key findings are summarized in Sect. 4.

175 **2** Atomistic modelling and simulations

In this work, the atom to atom interactions of carbon in
Graphene are simulated based on the Tersoff potential
(1989). Tersoff potential has been successfully applied
to predict mechanical properties of Graphene (Bu et al.
2009; Budarapu et al. 2015; Thomas and Ajith 2014;
Volokh 2012). The mathematical expression of the
bond energy of the atomistic model based on the Tersoff



Fig. 1 Variation of the normalized strength at the first bond break with cut-off distance at 0 and 300 K, with an initial crack length of 0.5L and when the lattice is oriented along 0°. The fracture strength at the first bond break is normalized with the corresponding value at $r_c = 2.1 \text{ Å}$

potential	can l	be expressed	as	(Tersoff	1989):	183
-----------	-------	--------------	----	----------	------	----	-----

$$V(r_{\alpha\beta}) = f_c(r_{\alpha\beta})[f_R(r_{\alpha\beta}) + b_{\alpha\beta}f_A(r_{\alpha\beta})]$$
18

$$f_R > f_c, \quad f_A > b_{\alpha\beta} \tag{1}$$

where $r_{\alpha\beta}$ is the distance between the atoms α and β . 186 The bond energy in the Tersoff framework is a com-187 bination of attractive (f_A) and repulsive (f_R) energy 188 functions, which are expressed in the form of the expo-189 nential Morse like functions; f_c is a smooth spherical 190 cut-off function around atom α based upon the dis-191 tance to the first nearest neighbour cell. Details of the 192 variables of potential function in Eq. (1) are explained 193 in "Appendix". Variation of the normalized fracture 194 strength with the effect of cut-off distance (r_c) at 0 195 and 300 K are plotted in Fig. 1. In Fig. 1, the fracture 196 strength at the first bond break is normalized with the 197 corresponding value at $r_c = 2.1$ Å. According to Fig. 1 198 and to (Shenderova et al. 2000; Zhao and Aluru 2010), 199 a cut-off distance of 2.1 Å is considered to reproduce 200 the physical observations, even at higher temperatures. 201 Hence, $r_c = 2.1 \text{ Å}$ is used in all the simulations of the 202 present work. 203

The main aim of the present work is to understand 204 the effect of lattice orientation on the crack initia-205 tion and growth mechanics and hence, on the mechan-206 ical properties of Graphene. To achieve this objec-207 tive, an uni-axial tensile deformation test of Graphene 208 is studied with varying lattice orientation and initial 209 crack length (a₀). Ten different lattice orientations of 210 Graphene are characterized by the following chiral vec-211

Deringer



Fig. 2 a Schematic of the edge crack model used in all the examples and **b** schematic showing the observed three fracture patterns along with the orientation angle, arm-chair and zig-zag directions

tors: (1,0), (1,1), (4,6), (5,8), (2,4), (2,5), (2,6), (1,4)
(2,11), (1,7). Thirteen different initial crack lengths are
also considered, namely: 0.025L, 0.05L, 0.1L, 0.15L,
0.2L, 0.25L, 0.33L, 0.4L, 0.5L, 0.6L, 0.7L, 0.8L, and
0.9L, where L is the width of the sample, see Fig. 2.

The hexagonal lattice structure of the Graphene 217 sheet with a lattice constant 2.45 Å, is considered to 218 develop the atomistic model. An initial edge crack is 219 created in the middle of the vertical side. The lattice 220 domain has overall dimensions of 432.01, Å (L) \times 221 432.31 Å (D), as shown in Fig. 2a. The correspond-222 ing full scale atomistic model consists of a set of atoms 223 ranging from 74,880 to 75,269, depending on the lat-224 tice orientation angle. To model the crack, the total 225 domain is partitioned into several regions, see Fig. 2a. 226 Atoms on the top and bottom edges of the domain 227 belong to regions 1 and 4, respectively. The crack in 228 the atomistic model is identified based on the distance 229 between two neighboring atoms. However, the initial 230 crack in the atomistic model is created by restricting 231 the interactions between the set of atoms on either side 232 of the crack surface, which is achieved by updating 233 the neighbour list accordingly. The degrees of free-234 dom along the x-direction of the left and right edge 235 atoms and along the y-direction of the top and bottom 236 edge atoms, are restrained. An initial velocity of 0.1 237 angstroms/pico-seconds (Å/ps) along the y-direction is 238 prescribed on the top and bottom edge atoms. A ramp 239 velocity profile as shown in Fig. 2a is adopted for the 240 rest of the domain. All the simulations in the present 241 work are carried out using the open source Large-242

scale Atomic/Molecular Massively Parallel Simulator (LAMMPS) software (Plimpton 1995). 244

In the present work, a 'load cycle' is defined as pre-245 scribing the velocity on the top and bottom edge atoms 246 for a specified time period, followed by an equilibration 247 for another specified time period. In each load cycle, the 248 prescribed velocity on the top and bottom edge atoms is 249 applied for another period of 1 ps, after which the sys-250 tem is equilibrated for a period of 1 ps. The computed 251 stress is the averaged stress estimated based on the Vir-252 ial theorem (Marc and McMillan 1985; Subramaniyan 253 and Sun 2008). The average virial stress (σ) over a vol-254 ume Ω with total number of atoms n^A is calculated 255 as 256

$$\boldsymbol{\sigma} = \frac{1}{\Omega} \left(\frac{1}{2} \sum_{\alpha=1}^{n^{A}} \sum_{\substack{\beta=1,\\\beta\neq\alpha}}^{n^{A}} \mathbf{r}_{\alpha\beta} \otimes \mathbf{f}_{\alpha\beta} - \sum_{\alpha=1}^{n^{A}} m_{\alpha} \dot{\mathbf{u}}_{\alpha} \otimes \dot{\mathbf{u}}_{\alpha} \right)$$
(2) 258

where m_{α} is the mass of atom α , **r** is the position vector, 259 **f** is the force vector and \mathbf{u}_{α} , $\dot{\mathbf{u}}_{\alpha}$ are the displacement and 260 velocity vectors of atom α , respectively. The definition 261 of Virial stress involves the instantaneous velocities 262 only due to thermal fluctuation. Therefore, the Virial 263 stress calculated from molecular dynamics simulations 264 has to be time averaged in order to arrive at the equiva-265 lent continuum Cauchy stress. In this work, Virial stress 266 is averaged over 500 time steps. Engineering strain is 267 used as a measure of deformation, which is defined as 268 $(l - l_0)/l_0$, where l is the instantaneous length of the 269

Deringer

Journal: 10704-FRAC MS: 0115 TYPESET DISK LE CP Disp.:2016/5/18 Pages: 18 Layout: Medium

vertical side and l_0 is its initial value obtained after 270 the first step of energy minimization corresponding to 271 the initial configuration. The time integration of the 272 equations of motion is carried out based on the Verlet 273 algorithm (Swope et al. 1982). The effect of numerical 274 stability has been investigated in Budarapu et al. (2015). 275 Budarapu et al. (2015) have reported that 1.0 fs is suf-276 ficient to study the mechanical behavior of Graphene 277 up to yielding. However, a much smaller time step is 278 required to predict the crack growth more accurately. 279 Since the objective is to study the yield properties, a 280 time step of 1.0 fs has been considered in the present 281 work. 282

All the simulations are performed under isothermal 283 loading conditions, at a temperature of $\approx 0 \text{ K} (0.1 \text{ K})$. In 284 the isothermal loading, the system temperature is main-285 tained constant. However, the application of the initial 286 velocities would lead to increase in the kinetic energy 287 and hence, the system temperature. Therefore, the 288 isothermal conditions in the present work are achieved 289 by velocity rescaling technique, where the velocities 290 at each time step are rescaled to maintain the constant 291 temperature of ≈ 0 K. The temperature of ≈ 0 K is con-292 sidered to avoid the influence of temperature on the 293 lattice orientations and crack length in the mechani-294 cal behavior of Graphene. Furthermore, to observe the 295 trends in mechanical properties with temperature, some 296 simulations are carried out at 300 K. The stress-strain 297 curves at ≈ 0 K are compared to the results at 300 K, as 298 explained in the results and discussion Sect. 3. How-299 ever, the complete study of the effect of temperature 300 on the mechanical response by varying lattice orienta-301 tions and crack length is beyond the scope of the present 302 work 303

The maximum Cauchy stress for a uni-axial tensile 304 test in the arm-chair and zig-zag direction is found to 305 be 110 and 121 GPa (Liu et al. 2007; Zhao et al. 2009), 306 respectively. The intrinsic breaking strength of perfect 307 Graphene is reported as 130 ± 10 GPa (Changgu et al. 308 2008; Zhao et al. 2009). Depending on the size of the 309 defect, the fracture stress of the defective Graphene 310 varies from 30 to 120 GPa (Khare et al. 2007; Zhang 311 et al. 2012b). However, the fracture stress is observed to 312 drop sharply from 120 GPa, for small initial defect sizes 313 and tend to 30-60 GPa, after a certain defect size. The 314 ability of a material containing a crack to resist fracture 315 is measured by its fracture toughness property. The crit-316 ical stress intensity factor (Peng et al. 2014) denoted by 317 $K_{IC} = \sigma_c \sqrt{\pi a_0}$, where σ_c is the critical stress of onset 318

of fracture and a_0 is the initial crack length, is conventionally used to characterize the fracture toughness of Graphene. As reported in Peng et al. (2014), the factor $\sigma_c \sqrt{a_0}$ remains constant irrespective of the initial crack length. Therefore, the fracture toughness of Graphene is expected to remain constant with respect to the size of the initial crack as well.

3 Results and discussions

326

327

3.1 Orientation dependent crack pattern

We performed the fracture simulations of 10 differ-328 ent lattice orientations with 13 different initial crack 329 lengths, to estimate the yield properties corresponding 330 to each combination of lattice orientation and initial 331 crack length. The yield properties, namely the yield 332 stress and yield strain are the stress and strain val-333 ues captured at the time of first bond break. Based on 334 the results, three different patterns of crack growth in 335 Graphene as labeled in Fig. 2b are observed. The pat-336 tern labeled as 1 is observed in the arm-chair Graphene 337 (0°) . A similar pattern is also observed in the 6.6°, and 338 10.9° orientations. The second pattern is noticed only 339 in the zig-zag Graphene, oriented at 30°. Whereas, the 340 third pattern is observed when the Graphene is ori-341 ented along the remaining six orientations, namely: 342 7.5°, 13.9°, 15.9°, 19.1°, 22.5°, and 23.4°. There-343 fore, we specifically select 0°, 13.9°, and 30° ori-344 entations to understand the crack growth patterns 345 and hence the variation of the associated mechanical 346 properties. 347

The initial atomic configuration at 0° orientation 348 is shown in Fig. 3a. Atoms around the crack tip are 349 marked with labels 'A' to 'P', where the color of the 350 atoms indicates their potential energy. A portion of the 351 atoms around the crack tip for the 0°, 13.9° and 30° 352 lattice orientations is also shown in Figs. 4a, 5a and 6a, 353 respectively. In the initial configuration, all the atoms 354 are assumed to have the same potential energy. The ini-355 tial crack is created by deleting the bonds between the 356 atoms and updating the neighbour list accordingly. The 357 dashed lines in Figs. 4a, 5a and 6a shows the deleted 358 bonds and hence the size of the initial crack. A strain 359 load is prescribed on a group of atoms along the top 360 and bottom surfaces of the lattice, as shown in Fig. 2a. 361 Therefore, based on the given loading and boundary 362 conditions, the bond D-C is the first loaded bond. Con-363

Deringer



Fig. 3 Atomic configurations around the crack tip in the initial and during the first and second bond break, when the Graphene lattice is oriented along 0° , 13.9° and 30°, in the *top*, *middle* and *bottom rows* respectively. The *dashed lines* indicate the broken bonds

Deringer

Journal: 10704-FRAC MS: 0115 TYPESET DISK LE CP Disp.: 2016/5/18 Pages: 18 Layout: Medium



Fig. 4 a Atom position in the initial configuration when the lattice is oriented along the 0° , along with the atoms around the crack tip. Variation of the **b** bond length, **c** bond angles and **d**

tinuous increase loading leads to stretching of the bonds 364 connecting the atoms D-C-E. When the bond length 365 reaches a certain threshold, the bond between D-C 366 breaks first at 213 ps, further transferring the load to 367 the next symmetric bond C-E, which finally breaks at 368 213.5 ps as shown in Fig. 3c. The load transfer is con-369 firmed by the shifting of the higher energy from atom D 370 to atom E, refer to Fig. 3a-c. The next bond to break is 371 E-F. Remaining bonds like A-B, B-G, D-N and N-O 372 are found to be stable with equilibrium bond length. 373

The initial configuration with the lattice oriented along the 13.9° is shown in Fig. 3d. In this orientation, the bond B–C is observed to be the first loaded,

strain along the y direction and the potential energy per atom, with time. The pictures in the bottom of **c** shows a closeup at the time of bond breaking. Plot **d** is generated for $a_0 = 0.5L$

which breaks at 212.5 ps as indicated in Fig. 3e. After the failure of the bond, the load is observed to be transferred to atom I from atom C through atom D. This leads to the failure of bond I–H at 232 ps, see Fig. 3f.

The initial configuration when the lattice is oriented along 30°, is shown in Fig. 3g. In this configuration, the bond connecting atoms G–B is observed to break first at 216 ps, followed by the failure of the symmetric bond M–F at 216.5 ps, refer to Fig. 3h, i.

Initial configurations of the lattice oriented along 0° , $_{387}$ 13.9° and 30° are shown in Figs. 4a, 5a and 6a, respectively. Stretching of various bonds with time in the 0° $_{389}$

🖄 Springer



Fig. 5 a Atom position in the initial configuration when the lattice is oriented along the 13.9° , along with the atoms around the crack tip. Variation of the **b** bond length, **c** bond angles and **d**

orientation is plotted in Fig. 4b, where the picture on 390 the top shows a closeup of the selected region. It can 391 be seen that the bond B-C starts initially to elongate, to 392 reach a bond length of 1.8 Å. Subsequently, the nearby 393 bonds also start elongating, to reach the bond length of 394 ≈ 1.8 Å. When all the bonds around the crack tip reach 395 the critical bond length, the bond C-D breaks first to 396 create the first fracture. Results indicate that the bond 397 length is the critical parameter to estimate fracture in 398 Graphene. The corresponding change of bond angles 399 with time are plotted in Fig. 4c. However, the bond 400 rotation plotted in Fig. 4c cannot be considered as a 401 parameter to estimate the bond breaking in Graphene. 402 This is due to the following reasons: (i) oscillations in 403 the bond angle until the first bond break; (ii) the bond 404

strain along the y direction and the potential energy per atom, with time. The pictures in the bottom of c shows a closeup at the time of bond breaking. Plot d is generated for $a_0 = 0.5L$

angles of the bonds around the crack tip change significantly due to reorientation of the bonds after the first bond break. Therefore, bond length can be considered as a parameter to predict the bond break in Graphene.

A similar trend and mechanical behaviour in bond 410 stretching is observed when the lattice is oriented along 411 the 13.9° and 30°, see Figs. 5b and 6b, respectively. 412 The bonds around the crack tip started to stretch first, 413 to reach a critical value. When all the bonds around the 414 crack tip reach the critical value, failure takes place. The 415 bond angles also follow a similar trend, but they cannot 416 be considered as a parameter to predict the fracture for 417 the reasons explained above. Variation of the stress in 418 the loading direction (σ_{yy}) and the potential energy per 419

Deringer

Author Proo

Journal: 10704-FRAC MS: 0115 🗌 TYPESET 🗌 DISK 🗌 LE 🗌 CP Disp.:2016/5/18 Pages: 18 Layout: Medium

Author Proo



Fig. 6 a Atom position in the initial configuration when the lattice is oriented along the 30° , along with the atoms around the crack tip. Variation of the **b** bond length, **c** bond angles and **d**

atom with time, when the lattice is oriented along 0° , 420 13.9° and 30°, is plotted in Figs. 4d, 5d and 6d, respec-421 tively. The first drop in stress as well as potential energy 422 is considered for the estimation of the yield stress and 423 yield strain of the materials. Based on Fig. 5d, it is inter-424 esting to note that the 13.9° lattice orientation shows a 425 continuous increase in stress as well as potential energy 426 even after the first bond break which is observed at 427 213.5 ps, refer to the closeup of Fig. 5b. The increase 428 in stress as well as potential energy is continued till 429 the second bond breaks at 232.5 ps. Therefore, results 430 indicate that special orientations of Graphene can lead 431 to improvement in the mechanical properties even after 432 first bond failure. 433

strain along the y direction and the potential energy per atom, with time. The pictures in the bottom in (c) shows a closeup at the time of bond breaking. Plot **d** is generated for $a_0 = 0.5L$

3.2 Lattice orientation dependent mechanical properties

In order to understand the effect of lattice orientation on 436 mechanical properties of Graphene, the tensile stress-437 strain curves have been generated for all the 10 different 438 orientations considered in the present work. Variation 439 of the stress with strain, for different lattice orienta-440 tions is plotted in Fig. 7. Based on Fig. 7, it is observed 441 that at zero strain all the orientations of Graphene have 442 zero stress, which indicates that no residual stress exist 443 in any of the configurations. Further strain controlled 444 loading leads to continuous increase in strain which 445 correspondingly leads to increase in stress. Due to the 446

Deringer

434

Fig. 7 Stress–strain plots of all the ten different configurations considered in the present work



increase in strain, the bond length of an initial relaxed 447 Graphene starts to increase. The atoms around the crack 448 tip possess the highest potential energy. As soon as the 449 bond lengths of the atoms around the crack tip reaches 450 a critical value, the breaking of first bond occurs, indi-451 cated by a drop in the stress, leading to the yielding of 452 Graphene. The corresponding stress and strain values 453 are designated as yield stress and yield strain, respec-454 tively. Fluctuations in the yield properties of Graphene 455 for different lattice orientations are observed. In order 456 to study the effect of lattice orientation on yielding, 457 yield stress and strain are plotted with lattice orienta-458 tions in Fig. 8. 459

Figure 8a, b shows the distribution of normalized 460 yield stress and normalized yield strain with vary-461 ing lattice orientations from 0° (arm-chair) to 30° 462 (zig-zag), respectively. The normalization is based on 463 the yield values at 0°. The arm-chair Graphene is 464 observed to possess the lowest yield stress, which 465 further increases with increase in lattice orientation 466 angle and reaches a maximum at 13.9°. Subsequent 467 increase in lattice orientation leads to the reduction in 468 yield stress until 22.5°. The yield stress is observed 469 to increase with the lattice orientation until 30°. From 470 Fig. 8a, the zig-zag configuration is observed to pos-471 sess a higher yield stress as compared to the arm-472 chair Graphene. Also a similar trend in yield strain is 473

observed. From Fig. 8b, it can be noticed that the arm-474 chair Graphene has a lower yield strain as compared 475 to the zig-zag configuration. Yield strain also shows 476 an increase in value by increasing lattice orientation 477 and reaches maximum at 13.9°. Subsequent increase 478 in lattice orientation leads to a drop in yield strain until 479 23.4°. Later on, the yield strain is observed to increase 480 until 30°. 481

The state of equilibrium energy of an atomistic sys-482 tem depends on the arrangement of atoms in that partic-483 ular configuration. The structure will be stable when the 484 system potential energy is minimum. In Graphene, the 485 bonds along the loading direction will undergo more 486 deformation and are responsible for failure with very 487 similar bond elongation at the fracture point (Zhao et al. 488 2009). Furthermore, the magnitude of the bond length 489 and bond angle variation in the zig-zag direction is 490 reported to be much larger than that of the arm-chair 491 direction (Zhao et al. 2009). This indicates that the 492 zig-zag configuration is energetically more stable and 493 absorbs more energy before fracture, as compared to the 494 arm-chair configuration. In other words, the arrange-495 ment of atoms in the arm-chair Graphene leads to an 496 energetically unstable configuration. In this work, we 497 observed that the stability increases with lattice orien-498 tation reaching the maximum at 13.9°. Therefore, the 499 potential energy is observed to be the lowest when the 500

Deringer

🙀 Journal: 10704-FRAC MS: 0115 🗌 TYPESET 🗌 DISK 🔤 LE 🔤 CP Disp.:2016/5/18 Pages: 18 Layout: Medium



Fig. 8 Distribution of the **a** normalized stress and **b** normalized strain with the lattice orientation. The plots are generated based on the results with $a_0 = 0.5L$



Fig. 9 Distribution of the **a** potential energy with strain and **b** a close up at the beginning, with zero strain. The plots are generated based on the initial potential energy of the system without any crack, after the minimization

lattice is oriented along 13.9°, as shown in Fig. 9. This
 explains the reasons for the highest potential energy of
 the arm-chair Graphene.

The lower fracture strength of arm-chair (0°) 504 Graphene as compared to the zig-zag (30°) Graphene 505 can be correlated to the system potential energy 506 plotted in Fig. 9. Based on Fig. 9b, the arm-chair 507 Graphene possesses the highest initial potential energy 508 of $-7.3631 \,\text{eV}$ /atom, as compared to other configura-509 tions considered in the present study. Due to the high-510 est initial potential energy of the arm-chair Graphene, 511 an early yielding is anticipated. Whereas, the zig-zag 512 Graphene is observed to possess an initial potential 513

energy of $-7.3657 \,\text{eV}$ /atom, which is lower than the 514 arm-chair Graphene. This indicates that the zig-zag 515 configuration is more stable and hence it can sustain 516 more strain, which leads to a higher fracture strength as 517 compared to the arm-chair Graphene. Interestingly, the 518 Graphene with chiral vector (2, 5) at 13.9° lattice orien-519 tation is found to be the most stable configuration with 520 an initial potential energy of -7.3663 eV/atom, out of 521 the 10 orientations considered in the present study. This 522 is further confirmed by the highest fracture strength of 523 Graphene when the lattice is oriented at 13.9°, refer to 524 Fig. 8a. 525

Interestingly, the crack patterns discussed in Sect. 3.1 526 for different lattice orientations can be correlated to the 527 yield stress and yield strain values. The pattern num-528 ber 1 in Fig. 2b is observed in 0° (arm-chair), 6.6°, 520 and 10.9° configurations. However, pattern number 2 is 530 observed only in 30° (zig-zag) orientation. The remain-531 ing lattice orientations (7.5°, 13.9°, 15.9°, 19.1°, 22.5°, 532 and 23.4°) are exhibiting the pattern number 3. In 533 the first pattern, the crack initiation and growth takes 534 place perpendicular to the loading direction, which cor-535 responds to the arm-chair (0°) configuration. Similar 536 crack initiation and growth perpendicular to the load-537 ing direction is observed in the third pattern as well, 538 which corresponds to the zig-zag (30°) configuration. 539 Therefore, the crack orientations between 0° to 10.9° 540 are mainly influenced by the arm-chair pattern. On 541 the other hand, crack orientations between 22.5° to 542 30° are mainly influenced by the zig-zag pattern. The 543 other orientations are influenced by the pattern num-544 ber 3. Results demonstrate that the pattern number 1 is 545 the weakest and the pattern number 2 is the strongest. 546 Based on the results, $\approx 10\%$ improvement as compared 547 to an initial arm-chair configuration in yield stress as 548 well as yield strain could be achieved by selecting the 549 lattice orientation in relation to the initial notch direc-550 tion. 551

552 3.3 Crack size dependent mechanical properties

The variation of stress with strain for arm-chair 553 Graphene at different percentage of crack length with 554 respect to the width of the sample is analyzed at 0K, 555 see Fig. 10a. The crack size is varied from $a_0 = 0.025L$ 556 to 0.90L with total 13 different initial simulated crack 557 lengths. With the increase in crack size, the amount 558 of energy required to break the bond around the crack 559 tip decreases. Hence, the yield stress is also observed 560 to be decreasing, as shown in Fig. 10a. It is observed 561 that until $a_0 = 0.10L$ of the crack size, the stiff-562 ness remains almost the same. The trend observed in 563 Fig. 10a is observed to be similar to the variation of 564 stress with strain for different hole sizes in Zhang et al. 565 (2012a). However, further increase in crack size leads 566 to decrease in yield stress as well as the stiffness. On 567 the other hand, the yield strain is noticed to decrease 568 initially with an increase in crack size. Whereas, after 569 a critical crack size, $a_0 \approx 0.20L$, the variation in the 570 yield strain remains almost constant at 0.05. Also sim-571

ilar variations are observed for the zig-zag Graphene at ≈ 0 K, as shown in Fig. 10c. 573

In order to understand the effect of temperature on 574 the mechanical properties of Graphene, preliminary 575 simulations are performed at room temperature 300 K, 576 for arm-chair and zig-zag orientations with varying 577 crack length, as shown in Fig. 10b, d, respectively. It is 578 observed that even at 300 K, the yield strain becomes 579 constant after a critical crack length. The variation of 580 the fracture toughness with a_0/L ratio for arm-chair 581 and zig-zag orientations at ≈ 0 and 300 K are plotted 582 in Fig. 10e. From these results, both the arm-chair as 583 well as the zig-zag orientations show almost constant 584 fracture toughness values at different temperatures. In 585 general, $a_0/L < 0.5$ can be considered to predict the 586 stress-intensity factor. From Fig. 10e, the median val-587 ues of mode I fracture toughness of arm-chair/zig-zag 588 Graphene is found to be 8.4 MPa \sqrt{m} at ≈ 0 K. The vari-589 ation in standard deviation is found to be 1.27. On the 590 other hand, at 300 K, the median values of mode I frac-591 ture toughness of arm-chair/zig-zag Graphene is found 592 to be 7.4 MPa \sqrt{m} . The variation in standard deviation is 593 found to be 1.52. A further detailed study on the stress 594 intensity factor of single layer Graphene at different 595 temperatures is beyond the scope of present work and 596 is left for future investigation. 597

Furthermore, to study the combined effect of dif-598 ferent orientations and crack sizes on the yield stress 599 and yield strain, 10 different lattice orientations with 600 13 different crack sizes are simulated. The distribution 601 of yield stress and yield strain, with crack length is 602 plotted in Fig. 11a, b, respectively. Figure 11c shows 603 the stress-strain distribution with lattice lattice orienta-604 tion in a three dimensional plot, for all the initial crack 605 lengths considered in this paper. Based on Fig. 10a, 606 for a given orientation, the yield stress decreases with 607 an increase in crack length, as discussed in Sect. 3.2. 608 Note that the discussion in Sect. 3.2 is valid for crack 609 sizes of $a_0 \ge 0.20L$. Smaller crack sizes shows differ-610 ent variation in yield stress with varying crack orienta-611 tions due to the involvement of the free surface near the 612 crack tip. The yield strain also shows a decreasing trend 613 with increase in crack size for a given orientation up to 614 $a_0 = 0.33L$ of crack length. A constant yield strain of 615 ≈ 0.05 is observed with further increase in crack size 616 up to $a_0 = 0.90L$. We report that this is one of the rea-617 sons for the softening of the Graphene, as displayed 618 by the decrease of stiffness with increase in crack 619 length. 620

Deringer

💢 Journal: 10704-FRAC MS: 0115 🗌 TYPESET 🗌 DISK 🗌 LE 🗌 CP Disp.:2016/5/18 Pages: 18 Layout: Medium



Fig. 10 Stress-strain plots for a, b arm-chair and c, d zig-zag Graphene at ≈0 and 300 K, respectively, for different crack lengths. e Variation of fracture toughness in arm-chair and zig-zag Graphene at ≈ 0 and 300 K

Deringer



Fig. 11 Variation of the **a** stress and **b** strain, with the lattice orientation, for various crack sizes. **c** Plots **a** and **b** are combined to generate the three dimensional plot, where the variation of

Furthermore, based on the yield stress and yield

does not show failure. This information can be utilized in the design of nano-devices for various strain sensor applications.

638

the yield stress and yield strain with the crack orientation can

be simultaneously monitored. The legends of plots a and b are

4 Conclusions

shown in (c)

Tensile deformation of two dimensional Graphene 539 structure with an edge crack has been simulated based 640 on molecular dynamics. Application of the load leads 641 to the bond deformation, resulting in an increase of 642 the system potential energy and hence the stress along 643 the loading direction. The severely stressed bonds 644 are breaking when the stress reaches a critical value, 645

strain plotted in Fig. 11a, b, a sudden decrease in 622 yield stress and yield strain can be noticed for crack 623 sizes <10 nm. However, for larger crack sizes a lin-624 ear decrease in yield stress is observed, whereas yield 625 strain remains constant. The behaviour is found to be 626 the same in all the lattice orientations considered in the 627 present study. Therefore, the behaviour of yield stress 628 as well as yield strain with crack length is insensitive to 629 the orientation, as shown in Fig. 12a, b. The variation 630 of the yield stress with yield strain for all the orienta-631 tions considered in the present work is plotted Fig. 12c. 632 Based on the results, a yield strain of ≈ 0.05 can be con-633 sidered as a critical strain value below which Graphene 634

🖄 Springer

621

Author Proo

Journal: 10704-FRAC MS: 0115 🗌 TYPESET 🗌 DISK 🗌 LE 🗌 CP Disp.:2016/5/18 Pages: 18 Layout: Medium

15

20

Crack length (nm)

(a)

25

30



Yield stress (GPa)

100

50

0 0.04

0.06



Fig. 12 Atomic configurations near the crack tip for Graphene orientations 0°, 13.9° and 30°

0.12

(2,11) (1,7) (1,0)

0.16

0.14

exposing the new set of atoms to resist the applied load.

0.08

0.1

Yield strain (c)

Ten different lattice orientations with thirteen dif-648 ferent initial crack lengths have been considered to 649 study their effect on the yield stress and yield strain 650 of Graphene. Graphene is observed fracture in three 651 particular patterns in all the lattice orientations, where 652 the arm-chair fracture pattern is observed to possess 653 the lowest yield properties. A sudden decrease in yield 654 stress and yield strain is noticed for crack sizes <10 nm. 655 However, for larger crack sizes a linear decrease in 656 yield stress is noticed, whereas a constant yield strain of 657 ≈ 0.05 is observed. Therefore, the yield strain of ≈ 0.05 658 can be considered as a critical strain value below which 659 Graphene does not show failure. This information can 660 be utilized in the design of nano-devices for various 661

strain sensor applications. Mode I fracture toughness 662 of arm-chair and zig-zag Graphene is estimated as 663 $8.4 \pm 1.27 \,\mathrm{MPa}\sqrt{m}$ and $7.4 \pm 1.52 \,\mathrm{MPa}\sqrt{m}$ at ≈ 0 664 and 300 K, respectively. Furthermore, Graphene can be 665 coated on the Silicon surface to enhance the mechan-666 ical (Berardone et al. 2014; Schröder et al. 2012) and 667 electrical characteristics the solar cells (Köntges et al. 668 2011; Paggi et al. 2011, 2013, 2014). The present study 669 will be useful in selecting the optimum orientation of 670 Graphene. 671

AcknowledgmentsB. Javvaji, D. R. Mahaptra and T. Rabczuk672gratefully acknowledge the financial support from the Germany673Science Foundation (DFG) and from the International Research674Staff Exchange Scheme (IRSES), FP7-PEOPLE-2010-IRSES,675through the project 'MultiFrac'. M. Paggi and P. R. Budarapu676acknowledges the funding from the European Research Coun-677

🖄 Springer

P. R. Budarapu et al.

739

740

745

746

747

748

749

750

753

757

758

759

760

761

762

cil (ERC), Grant No. 306622 through the ERC Starting Grant 678 "Multi-field and multi-scale Computational Approach to Design 679 and Durability of PhotoVoltaic Modules"-CA2PVM. B. Javvaji 680 and D. R. Mahapatra thankfully acknowledge the use of com-681 putational facilities at the ACECOST Computational Science 682 Lab, Department of Aerospace Engineering, IISc and funding 683 under ACECOST Phase-III program of Aeronautics Research 684 and Development Board, India. Zi appreciates the financial sup-685 port through Grant No. 20133010021770, from the New & 686 Renewable Energy Core Technology Program of the Korea Insti-687 tute of Energy Technology Evaluation and Planning (KETEP), 688 Ministry of Trade, Industry & Energy, Republic of Korea. 689

Appendix: Tersoff potential function

The mathematical expression of the bond energy based 691 on the Tersoff potential is given in Eq. (1). The bond 692 energy in the Tersoff framework is a combination 693 of repulsive (f_R) energy function which is exponen-694 tially decaying and attractive (f_A) energy function that 695 exponentially increases; with the increase of distance 696 between the atoms. f_c is a smooth spherical cutoff func-697 tion around atom α based upon the distance to the first 698 nearest-neighbor shell. The function f_c in Eq. (1) is 699 defined as Tersoff (1989): 700

$$f_{c}(r_{\alpha\beta}) = \begin{cases} 1 & \text{when } r_{\alpha\beta} < \mathcal{R}_{\alpha\beta} \\ \frac{1}{2} + \frac{1}{2} \cos\left(\frac{\pi(r_{\alpha\beta} - \mathcal{R}_{\alpha\beta})}{(\mathcal{S}_{\alpha\beta} - \mathcal{R}_{\alpha\beta})}\right) & \text{when } \mathcal{R}_{\alpha\beta} < r_{\alpha\beta} < \mathcal{S}_{\alpha\beta} \\ 0 & \text{when } r_{\alpha\beta} > \mathcal{S}_{\alpha\beta} \end{cases}$$

from Eq. (3), f_c returns a value of 1 if $r_{\alpha\beta}$ is less than 704 $\mathcal{R}_{\alpha\beta}$ and 0 when $r_{\alpha\beta}$ greater than $\mathcal{S}_{\alpha\beta}$. The values of the 705 constants $\mathcal{R}_{\alpha\beta} = \sqrt{\mathcal{R}_{\alpha}\mathcal{R}_{\beta}}$ and $\mathcal{S}_{\alpha\beta} = \sqrt{\mathcal{S}_{\alpha}\mathcal{S}_{\beta}}$, (where 706 α and β can be two different atom types, like Silicon 707 and Carbon) are listed for Silicon and Carbon atoms in 708 Tersoff (1989). The repulsive and attractive potential 709 energies are tuned with the parameters $\mathcal{A}_{\alpha\beta}$ and $\mathcal{B}_{\alpha\beta}$, 710 respectively. The repulsive potential energy is defined 711 as Tersoff (1989) 712

$$f_R(r_{\alpha\beta}) = \mathcal{A}_{\alpha\beta} e^{-\mathcal{D}_{\alpha\beta}r_{\alpha\beta}}$$
(4)

and the attractive potential energy is estimated from 714 Tersoff (1989) 715

⁷¹⁶
$$f_A(r_{\alpha\beta}) = -\mathcal{B}_{\alpha\beta}e^{-\mathcal{E}_{\alpha\beta}r_{\alpha\beta}}$$
 (5)

where $\mathcal{A} = \sqrt{\mathcal{A}_{\alpha}\mathcal{A}_{\beta}}, \, \mathcal{B} = \sqrt{\mathcal{B}_{\alpha}\mathcal{B}_{\beta}}, \, \mathcal{D}_{\alpha\beta} = (\mathcal{D}_{\alpha} + \mathcal{D}_{\alpha\beta})$ 717 $\mathcal{D}_{\beta})/2$ and $\mathcal{E}_{\alpha\beta} = (\mathcal{E}_{\alpha} + \mathcal{E}_{\beta})/2$, in Eqs. (4) and (5) 718 are constants. The variable $b_{\alpha\beta}$ in Eq. (1) is designed 719

to represent the bond strength of the potential. $b_{\alpha\beta}$ is 720 inversely proportional to the coordination number and 721 is defined as Tersoff (1989) 722

$$b_{\alpha\beta} = \xi_{\alpha\beta} \left(1 + \mathcal{P}_{\alpha}^{q_{\alpha}} \zeta_{\alpha\beta}^{q_{\alpha}} \right)^{-1/2q_{\alpha}} \tag{6}$$

where \mathcal{P} and q are the constants. $\zeta_{\alpha\beta}$ provides a 724 weighted measure of the number of other bonds (γ) 725 competing with the bond α - β , which is defined as Ter-726 soff (1989) 727

$$\zeta_{\alpha\beta} = \sum_{\gamma \neq \alpha,\beta} f_c(r_{\alpha\gamma}) g(\theta_{\alpha\beta\gamma})$$
(7) 728

where $\xi_{\alpha\beta}$ is the strengthening or weakening factor of 729 the hetero-polar bonds and $g(\theta_{\alpha\beta\gamma})$ provides a mea-730 sure of dependence on the bonding angle $\theta_{\alpha\beta\gamma}$, sub-731 tended at atom α by atoms β and γ . The variable 732 $g(\theta_{\alpha\beta\gamma})$ is included to stabilize the atomic geome-733 try under shear operations and to provide an effective 734 coordination contribution based on the elastic energy 735 of the current configuration, which is defined as Tersoff 736 (1989)737

$$g\left(\theta_{\alpha\beta\gamma}\right) = 1 + \frac{c_{\alpha}^2}{d_{\alpha}^2} - \frac{c_{\alpha}^2}{d_{\alpha}^2 + \left(h_{\alpha} - \cos\left(\theta_{\alpha\beta\gamma}\right)\right)^2} \quad (8) \quad ^{738}$$

where c_{α} , d_{α} and h_{α} are the constants.

References

- Ansari R, Ajori S, Motevalli B (2012) Mechanical properties 741 of defective single-layered graphene sheets via molecu-742 lar dynamics simulation. Superlattices Microstruct 51:274-743 289 744
- Berardone I, Corrado M, Paggi M (2014) A generalized electric model for mono and polycrystalline silicon in the presence of cracks and random defects. Energy Procedia 55:22-29
- Bu H, Chen Y, Zou M, Yi H, Bi K, Ni Z (2009) Atomistic simulations of mechanical properties of graphene nanoribbons. Phys Lett A 373:3359-3362
- Budarapu P, Javvaji B, Sutrakar V, Mahapatra D, Zi G, Rabczuk 751 T (2015) Crack propagation in graphene. J Appl Phys 752 118:382-395
- Budarapu P, Rammohan B, Vijay S, Satish B, Raghunathan R 754 (2009) Aero-elastic analysis of stiffened composite wing 755 structure. J Vib Eng Technol 8(3):255-264 756
- Budarapu P, Sudhir S, Brahmanandam J, Mahapatra D (2014c) Vibration analysis of multi-walled carbon nanotubes embedded in elastic medium. Front Struct Civil Eng 8(2):151-159
- Cao G (2014) Atomistic studies of mechanical properties of graphene. Polymers 6:2404-2432
- Changgu L, Xiaoding W, Jeffrey WK, James H (2008) Mea-763 surement of the elastic properties and intrinsic strength of 764 monolayer graphene. Science 321(5887):385-388 765

🖉 Springer

Journal: 10704-FRAC MS: 0115 TYPESET DISK LE CP Disp.:2016/5/18 Pages: 18 Layout: Medium

- Chen K, Bin S, Yonghai Y, Juanjuan Q, Lin G (2015a) Binary syn-766 ergy strengthening and toughening of bio-inspired nacre-767 like graphene oxide/sodium alginate composite paper. ACS 768 Nano 9(8):8165-8175 769
- Chen M, Quek S, Sha Z, Chiu C, Pei Q, Zhang Y (2015b) Effects 770 of grain size, temperature and strain rate on the mechanical 771 properties of polycrystalline graphene -a molecular dynam-772 ics study. Carbon 85:135-146 773
 - Chuvilin A, Meyer J, Algara-Siller G, Kaiser U (2009) From graphene constrictions to single carbon chains. New J Phys 11:083019
 - Datta D, Nadimpalli S, Yinfeng L, Shenoy V (2015) Effect of crack length and orientation on the mixed-mode fracture behavior of graphene. Extreme Mech Lett 5:10-17
 - Fengnian X, Han W, Di X, Madan D, Ashwin R (2014) Twodimensional material nanophotonics. Nat Photonics 8:899-907
- Fiori G, Bonaccorso F, Iannaccone G, Palacios T, Neumaier 783 D, Seabaugh A, Banerjee S, Colombo L (2014) Electron-784 ics based on two-dimensional materials. Nat Nanotechnol 785 9.768 - 779786
- Gamboa A, Vignoles G, Leyssale J-M (2015) On the prediction 787 of graphene's elastic properties with reactive empirical bond 788 order potentials. Carbon 89:176-187 789
- Geim A (2009) Graphene: status and prospects. Science 790 324:1530-1534 791
- Grantab R, Shenoy V, Ruoff R (2010) Anomalous strength char-792 acteristics of tilt grain boundaries in graphene. Science 793 330:946-948 794
- Hadden C, Klimek-McDonald D, Pineda E, King J, Reichanadter 795 A, Miskioglu I, Gowtham S, Odegard G (2015) Mechani-796 797 cal properties of graphene nanoplatelet/carbon fiber/epoxy hybrid composites: Multiscale modeling and experiments. 798 Carbon 95:100–112 790
- Huhu C, Chuangang H, Yang Z, Liangti Q (2014) Graphene fiber: 800 a new material platform for unique applications. NPG Asia 801 Mater 6:e113 802
- Jhon Y, Jhom Y, Yoem G, Jhon M (2014) Orientation dependence 803 of the fracture behavior of graphene. Carbon 66:619-628 804
- Jhon Y, Zhu S, Ahn J, Jhon M (2012) The mechanical responses 805 806 of tilted and non-tilted grain boundaries in graphene. Carbon 50:3708-3716 807
- Jin C, Lan H, Peng L, Suenaga K, Iijima S (2009) Deriving carbon 808 atomic chains from graphene. Phys Rev Lett 102:205501 809
- Khare R, Mielke S, Paci J, Zhang S, Ballarini R, Schatz 810 G, Belytschko T (2007) Coupled quantum mechani-811 cal/molecular mechanical modeling of the fracture of defec-812 tive carbon nanotubes and graphene sheets. Phys Rev B 813 75.075412 814
- Kim K, Artyukhov V, Regan W, Liu Y, Crommie M, Yakobson 815 B, Zettl A (2012) Ripping graphene: preferred directions. 816 Nano Lett 12:293-297 817
- Kim Y, Lee J, Yeom M, Shin J, Kim H, Cui Y, Kysar J, Hone 818
- J, Jung Y, Jeon S, Han S (2013) Strengthening effect of 819 single-atomic-layer graphene in metal-graphene nanolay-820 ered composites. Nat Commun 4:2114 821
- Kinam K, Jae-Young C, Taek K, Seong-Ho C, Hyun-Jong C 822 (2011) A role for graphene in silicon-based semiconductor 823 devices. Nature 479:338-344 824

Köntges M, Kunze I, Kajari-Schröder S, Breitenmoser X, Bjrnek-825 lett B (2011) The risk of power loss in crystalline silicon 826 based photovoltaic modules due to microcracks. Sol Energy 827 Mater Sol Cells 95:1131–1137

828

829

830

839

840

841

842

847

848

849

850

851

852

853

854

855

856

857

858

859

860

861

862

863

864

865

866

867

868

869

870

871

872

873

874

875

876

877

878

879

880

881

2

- Kostarelos K, Novoselov K (2014) Graphene devices for life. Nat Nanotechnol 9:744-745
- Kravets V, Jalil R, Kim Y-J, Ansell D, Aznakayeva D, Thack-831 ray B, Britnell L, Belle B, Withers F, Radko I, Han Z, 832 Bozhevolnyi S, Novoselov K, Geim A, Grigorenko A (2014) 833 Graphene-protected copper and silver plasmonics. Sci Rep 834 4:5517 835
- Liu F, Ming P, Li J (2007) Ab initio calculation of ideal strength 836 and phonon instability of graphene under tension. Phys Rev 837 B 76:064120 838
- Liu J (2014) Charging graphene for energy. Nat Nanotechnol 9:739-741
- Marc G, McMillan W (1985) The virial theorem. Adv Chem Phys 58:209
- Mics Z, Tielrooij K-J, Parvez K, Jensen S, Ivanov I, Feng X, 843 M"ullen K, Bonn M, Turchinovich D (2015) Thermody-844 namic picture of ultrafast charge transport in graphene. Nat 845 Commun 6:7655 846
- Morpurgo A (2015) Ten years of nature physics: the abc of 2D materials. Nat Phys 11:625-626
- Paggi M, Berardone I, Infuso A, Corrado M (2014) Fatigue degradation and electric recovery in silicon solar cells embedded in photovoltaic modules. Sci Rep 4:4506
- Paggi M, Corrado M, Rodriguez MA (2013) A multi-physics and multi-scale numerical approach to microcracking and power-loss in photovoltaic modules. Compos Struct 95:630-638
- Paggi M, Kajari-Schröder S, Eitner U (2011) Thermomechanical deformations in photovoltaic laminates. J Strain Anal Eng Des 46(8):772-782
- Pei Q, Zhang Y, Shenoy V (2010) A molecular dynamics study of the mechanical properties of hydrogen functionalized graphene. Carbon 48:898-904
- Peng Z, Lulu M, Feifei F, Zhi Z, Cheng P, Phillip EL, Zheng L, Yongji G, Jiangnan Z, Xingxiang Z, Pulickel MA, Ting Z, Jun L (2014) Fracture toughness of graphene. Nat Commun 5:3782
- Plimpton S (1995) Fast parallel algorithms for short-range molecular dynamics. J Comput Phys 117:1-19
- Pospischil A, Furchi M, Mueller T (2014) Solar-energy conversion and light emission in an atomic monolayer p-n diode. Nat Nanotechnol 9:257-261
- Quan L, Zhen T, Xueqian Z, Ranjan S, Liangliang D, Jianqiang G, Jiaguang H, Weili Z (2015) Active graphene-silicon hybrid diode for terahertz waves. Nat Commun 6:7082
- Rodrigues G, Zelenovskiy P, Romanyuk K, Luchkin S, Kopelevich Y, Kholkin A (2015) Strong piezoelectricity in singlelayer graphene deposited on sio₂ grating substrates. Nat Commun 6:7572
- Santanu S, Elena B, Haddon RC (2012) Covalent chemistry in graphene electronics. Mater Today 15(6):276-285
- Sarma D, Adam S, Hwang E, Rossi E (2011) Electronic transport in two dimensional graphene. Rev Mod Phys 83:407-470
- Schröder SK, Kunze I, Köntges M (2012) Criticality of cracks 882 in PV modules. Energy Procedia 27:658-663 883

774

775

776

777

778

779

780

781

931

932

933

934

935

939

945

946

947

948

949

950

951

952

953

954

955

956

957

958

959

960

Author Proo

886

887

888

889

890

891

892

893

894

895

896

897

898

899

900

901

902

- Schwierz F (2010) Graphene transistors. Nat Nanotechnol 884 5:487-496 885
 - Shenderova O, Brenner D, Omeltchenko A, Su X, Yang L (2000) Atomistic modeling of the fracture of polycrystalline dia-
 - mond. Phys Rev B 61(6):3877-3888
 - Shin S, Choi H, Shin J, Bae D (2015) Strengthening behavior of few-layered graphene/ aluminum composites. Carbon 82:143-151
 - Son I, Park J, Kwon S, Park S, R"ummeli M, Bachmatiuk A, Song H, Ku J, Choi J, Choi J, Doo S-G, Chang H (2015) Silicon carbide-free graphene growth on silicon for lithium-ion battery with high volumetric energy density. Nat Commun 6:7393
 - Subramaniyan A, Sun C (2008) Continuum interpretation of virial stress in molecular simulations. Int J Solids Struct 45:4340-4346
 - Sun X-Y, Hu H, Cao C, Xua Y-J (2015) Anisotropic vacancydefect-induced fracture strength loss of graphene. RSC Adv 5:13623-13627
- Swope W, Anderson H, Berens P, Wilson K (1982) A computer 903 simulation method for the calculation of equilibrium con-904 stants for the formation of physical clusters of molecules: 905 application to small water clusters. J Chem Phys 76:637 906
- Tersoff J (1989) Modeling solid-state chemistry: interatomic 907 potentials for multicomponent systems. Phys Rev B 908 39(8):5566-5568 909
- Thomas S, Ajith K (2014) Molecular dynamics simulation of 910 the thermo-mechanical properties of monolayer graphene 911 sheet. Proc Mater Sci 5:489-498 912
- Tiwary C, Javvaji B, Kumar C, Mahapatra D, Ozden S, Ajayan 913 P, Chattopadhyay K (2015a) Chemical-free graphene by 914 915 unzipping carbon nanotubes using cryo-milling. Carbon 217 - 224916
- Tiwary C, Vishnu D, Kole A, Brahmanandam J, Mahapatra D, 917 Kumbhakar P, Chattopadhyay K (2015b) Stabilization of the 918 high-temperature and high-pressure cubic phase of ZnO by 919 temperature-controlled milling. J Mater Sci. doi:10.1007/ 920 s10853-015-9394-1 921
- Traversi F, Raillon C, Benameur S, Liu K, Khlybov S, Tosun M, 922 Krasnozhon D, Kis A, Radenovic A (2014) Detecting the 923 924 translocation of DNA through a nanopore using graphene nanoribbons. Nature Nanotechnol 8:939-945 925
- Vadukumpully S, Paul J, Mahanta N, Valiyaveettil S (2011) Flex-926 ible conductive graphene/poly(vinyl chloride) composite 927 thin films with high mechanical strength and thermal sta-928
- bility. Carbon 49:198-205 929

- Volokh KY (2012) On the strength of graphene. J Appl Mech 79(6):064501-064501. doi:10.1115/1.4005582
- Weiwei Z, Yanlei W, Zhangting W, Wenhui W, Kedong B, Zheng L, Juekuan Y, Yunfei C, Zhiping X, Zhenhua N (2015) Defect-engineered heat transport in graphene: a route to high efficient thermal rectification. Sci Rep 5:11962
- Wen S, Yuqi Y, Jiangnan S, Hua C (2012) A graphene-based com-936 posite material noncovalently functionalized with a chemi-937 luminescence reagent: synthesis and intrinsic chemilumi-938 nescence activity. Chem Commun 48:2894-2896
- Xue T, Peng B, Xue M, Zhong X, Chiu C-Y, Yang S, Qu Y, 940 Ruan L, Jiang S, Dubin S, Kaner R, Zink J, Meyerhoff M, 941 Duan X, Huang Y (2014) Integration of molecular and enzy-942 matic catalysts on graphene for biomimetic generation of 943 antithrombotic species. Nat Commun 5:3200 944
- Xuechao Y, Youde S, Tao L, Tao(Tom) W, Wang QJ (2015) Photocurrent generation in lateral graphene p-n junction created by electron-beam irradiation. Sci Rep 5:12014
- Ying-Yan Z, Qing-Xiang P, Yiu-Wing M, Yuan-Tong G (2014) Temperature and strain-rate dependent fracture strength of graphynes. J Phys D Appl Phys 47(42):425301
- Zan L, Genlian F, Qiang G, Zhiqiang L, Yishi S, Di Z (2015) Synergistic strengthening effect of graphene-carbon nanotube hybrid structure in aluminum matrix composites. Carbon 95:419-427
- Zhang H, Wu J, He J, Zhang Z (2012a) Effect of hole size on the fracture of graphene nanomesh. In: Proceeding of the 19th European conference on fracture, ISBN 978-5-905576-18-8
- Zhang T, Li X, Kadkhodaei S, Gao H (2012b) Flaw insensitive fracture in nanocrystalline graphene. Nano Lett 12:4605-4610
- Zhang Y, Zhao J, Wie N, Jiang J, Rabczuk T (2013) Effects of 961 the dispersion of polymer wrapped two neighbouring sin-962 gle walled carbon nanotubes (SWNTs) on nanoengineering 963 load transfer. Compos Part B Eng 45(1):1714-1721
- Zhao H, Aluru N (2010) Temperature and strain-rate dependent fracture strength of graphene. J Appl Phys 108:064321
- Zhao H, Min K, Aluru N (2009) Size and chirality dependent elastic properties of graphene nanoribbons under uniaxial tension. Nano Lett 9(8):3012-3015

🖉 Springer

Journal: 10704-FRAC MS: 0115 TYPESET DISK LE CP Disp.:2016/5/18 Pages: 18 Layout: Medium

968